

Description

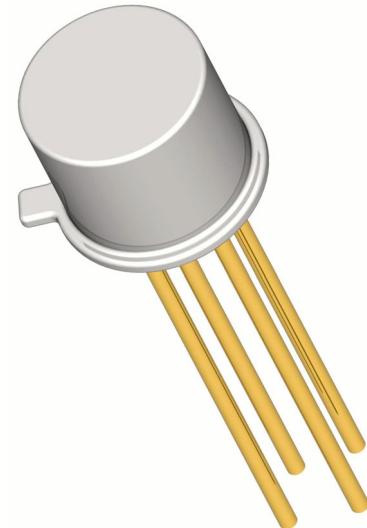
SEMICOA Corporation offers:

- Screening and processing per MIL-PRF-19500
- JAN level (2N2857J)
- JANTX level (2N2857JX)
- JANTXV level (2N2857JV)
- JANS level (2N2857JS)
- JANSR level (2N2857JSR)
- JANSF level (2N2857JSF)
- QCI to the applicable level
- 100% die visual inspection per MIL-STD-750 method 2072 for JANTXV and JANS
- Radiation testing (total dose) upon request

Please contact SEMICOA for special configurations
www.SEMICOA.com or (714) 979-1900

Applications

- Ultra-High frequency transistor
- Low power
- NPN silicon transistor

**Features**

- Hermetically sealed TO-72 metal can
- Also available in chip configuration
- Chip geometry 0011
- Reference document: MIL-PRF-19500/343

Benefits

- Qualification Levels: JAN, JANTX, JANTXV, JANS, JANSR and JANSF
- Radiation testing available

Absolute Maximum Ratings		T_c = 25°C unless otherwise specified	
Parameter	Symbol	Rating	Unit
Collector-Emitter Voltage	V _{CEO}	15	Volts
Collector-Base Voltage	V _{CBO}	30	Volts
Emitter-Base Voltage	V _{EBO}	3	Volts
Collector Current, Continuous	I _C	40	mA
Power Dissipation, T _A = 25°C Derate linearly above 25°C	P _T	200 1.14	mW mW/°C
Power Dissipation, T _c = 25°C Derate linearly above 25°C	P _T	300 1.71	mW mW/°C
Operating Junction Temperature	T _J	-65 to +200	°C
Storage Temperature	T _{STG}	-65 to +200	°C

ELECTRICAL CHARACTERISTICS

characteristics specified at $T_A = 25^\circ\text{C}$

Off Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Collector-Emitter Breakdown Voltage	$V_{(\text{BR})\text{CEO}}$	$I_C = 3 \text{ mA}$	15			Volts
Collector-Base Cutoff Current	$I_{\text{CBO}1}$	$V_{\text{CB}} = 15 \text{ Volts}$			10	nA
Collector-Base Cutoff Current	$I_{\text{CBO}3}$	$V_{\text{CB}} = 30 \text{ Volts}$			1	μA
Collector-Base Cutoff Current	$I_{\text{CBO}2}$	$V_{\text{CB}} = 15 \text{ Volts}, T_A = 150^\circ\text{C}$			1	μA
Collector-Emitter Cutoff Current	I_{CES}	$V_{\text{CE}} = 16 \text{ Volts}$			100	nA
Emitter-Base Cutoff Current	$I_{\text{EBO}1}$	$V_{\text{EB}} = 3 \text{ Volts}$			10	μA

On Characteristics

Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
DC Current Gain	$h_{\text{FE}1}$ $h_{\text{FE}2}$	$I_C = 3 \text{ mA}, V_{\text{CE}} = 1 \text{ Volts}$ $I_C = 3 \text{ mA}, V_{\text{CE}} = 1 \text{ Volts}$ $T_A = -55^\circ\text{C}$	30 10		150	
Base-Emitter Saturation Voltage	V_{BEsat}	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$			1.0	Volts
Collector-Emitter Saturation Voltage	V_{CESat}	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$			0.4	Volts

Dynamic Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Magnitude – Common Emitter, Short Circuit Forward Current Transfer Ratio	$ h_{\text{FE}} $	$V_{\text{CE}} = 6 \text{ Volts}, I_C = 5 \text{ mA}, f = 100 \text{ MHz}$	10		21	
Small Signal Short Circuit Forward Current Transfer Ratio	h_{FE}	$V_{\text{CE}} = 6 \text{ Volts}, I_C = 2 \text{ mA}, f = 1 \text{ kHz}$	50		220	
Collector to Base Feedback Capacitance	C_{CB}	$V_{\text{CB}} = 10 \text{ Volts}, I_E = 0 \text{ mA}, 100 \text{ kHz} < f < 1 \text{ MHz}$			1	pF
Collector Base time constant	$r_b' C_C$	$V_{\text{CB}} = 6 \text{ Volts}, I_E = 2 \text{ mA}, f = 31.9 \text{ MHz}$	4		15	ps
Small Signal Power Gain	G_{pe}	$V_{\text{CE}} = 6 \text{ Volts}, I_E = 1.5 \text{ mA}, f = 450 \text{ MHz}$	12.5		21	MHz
Noise Figure	F	$V_{\text{CE}} = 6 \text{ Volts}, I_C = 1.5 \text{ mA}, f < 450 \text{ MHz}, R_g = 50 \Omega$			4.5	dB

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